Edexcel Physics A-level Topic 3: Electric Circuits

Key Points

## Current

Current is defined as the rate of flow of charge in a circuit. It is measured in Amperes. You should be aware of two different ways of describing current flow:

1. Electron flow is from negative to positive and is the direction that electrons actually flow in a circuit
2. Conventional current flow is from positive to negative and is more commonly used to describe the direction of current

As an equation, current is defined as:

$$
I=\frac{\Delta Q}{\Delta t}
$$

1 Ampere is the current flow when 1 Coulomb of charge passes a point each second.

## 長PMT <br> Potential Difference

Potential difference is equal to the work done per coulomb of charge travelling in a circuit. As an equation this is defined as:

$$
V=\frac{W}{Q}
$$

It is measured in Volts, where 1 Volt is equal to 1 Joule of work being done by each Coulomb of charge.

To measure the potential difference over a specific component, a voltmeter can be used. It should be connected in parallel over the component.

An ideal voltmeter has infinite resistance, so that no current is drawn from the circuit.

## 家PMT <br> Resistance

Resistance is a measure of how difficult it is for current to flow in a circuit. It is directly proportional to the potential difference in a circuit, and inversely proportional to the current flow. As an equation it is defined as:

$$
R=\frac{V}{I}
$$

It is measured in Ohms.

An ohmic conductor is a conductor which follows Ohm's law, meaning that the current flowing through it is directly proportional to potential difference, when it is held at a constant temperature.


Resistivity
The resistivity of a material is a measure of how easily it allows charge to flow through it and depends on several different factors. They are:

1. Cross sectional area - the greater the area, the easier the passage of electrons
2. Length - the longer the length, the harder it is to send a current through it 3. Resistance - the larger the resistance through a material, the larger its resistivity
Combining these factors allows an equation for resistivity to be formed:

$$
\rho=\frac{R A}{L}
$$

The unit for resistivity is $\mathbf{\Omega} \mathbf{m}$.

## EPMT

## Current and Potential

The current (I) through a wire can be measured using the following equation:

$$
I=n q v A
$$

Where...
$\boldsymbol{n}=$ the density of charge carriers $\left(\mathrm{m}^{-3}\right)$
Therefore, materials have a large range of $\mathbf{q}=$ is the charge of charge carriers (usually $1.6 \times 10^{-16} \mathrm{C}$ ) resistivities since the density of charge carriers
(free electrons) in them varies greatly.

$$
\mathbf{v}=\text { the velocity of the charge carriers }\left(\mathrm{ms}^{-1}\right)
$$

$$
\mathbf{A}=\text { the area of the wire }\left(\mathrm{m}^{2}\right)
$$

When you increase the length of a wire, the resistance across it also increases following the equation:

$$
R=\frac{\rho L}{A}
$$

As potential difference $(V)$ is equal to the product of current and resistance $(V=I R)$, the potential across the wire also increases with length.

## Superconductors and Semiconductors

Superconductors are materials which have zero resistivity at and below a critical temperature. This temperature differs for each material, but currently are too low to be used effectively. If materials with high enough critical temperatures can be developed, they
could be used in electricity transmission to reduce energy loss as well as in the production of extremely strong magnetic fields.

Semiconductors are components for which the resistance changes depending on external conditions. The two main types you need to know about are:

1. Light Dependant Resistors (LDRs) are light sensitive components - when light intensity increases, electrons in the LDR are released and so its resistance decreases. This is because the number of conduction electrons increases.
2. Thermistors are temperature sensitive components - when their temperature increases, electrons in the thermistor are released and so its resistance decreases. This is because the number of conduction electrons increases.

## Power

Power is defined as the rate of energy transfer. It can be calculated using:

$$
P=\frac{W}{t}
$$

It can also be defined by combining the above equation with the equations defining potential difference, resistance and current to give:

$$
P=I V=I^{2} R=\frac{V^{2}}{R}
$$

The unit of power is the Watt, where 1 Watt is the power dissipated when 1 joule of energy is transferred each second.

## I-V Characteristics

You should be familiar with the two I-V characteristics below, as well as with the straight-line ohmic conductor graph.

Filament Lamp
When a filament bulb is used, as current is increased, the temperature of the filament increases. This causes the metal ions to vibrate with more kinetic energy and consequently, makes it harder for the charge carriers to pass through. This means the resistance increases.

Diode
Diodes are components that only let current flow through in one direction. In the opposite direction the resistance is very high and means current can't flow through. In the correct direction, diodes have a
threshold voltage of around

0.6 V , after which current can
flow through normally.

## Series and Parallel Circuits

Series circuits are ones where all the components are part of the same loop. You need to know that:

- The current is the same in all positions in a series circuit
- The potential difference over the loop is split between all the components, in the ratio of their resistances

Parallel circuits are ones where the components are in adjacent loops. You need to know that:

- The potential difference over each loop is the same
- The current is split between each branch and so is different in different parts of the circuit


## Kirchoff's Laws

Energy and charge are conserved in circuits which means that e.m.f and current are too (as they're related to energy and charge respectively).

## Kirchhoff's 1st Law:

The total current entering a junction is equal to the total current leaving it.

$$
\begin{aligned}
& I_{t}=I_{1}+I_{2}+I_{3} \ldots \\
& \frac{V}{R_{t}}=\frac{V}{R_{1}}+\frac{V}{R_{2}}+\frac{V}{R_{3}} \\
& \frac{1}{R_{t}}=\frac{1}{R_{1}}+\frac{1}{R_{2}}+\frac{1}{R_{3}}
\end{aligned}
$$

From this we can derive total resistance in a parallel circuit as shown above.

## Kirchhoff's 2nd Law:

The sum of e.m.f in any loop of the circuit is equal to the sum of the
p.d's of each component.

$$
\begin{gathered}
\varepsilon=\Sigma I \mathrm{R} \\
\mathrm{IR}_{\mathrm{t}}=\mathrm{IR}_{1}+\mathrm{IR}_{2}+\mathrm{IR}_{3} \ldots \\
\mathrm{R}_{\mathrm{t}}=\mathrm{R}_{1}+\mathrm{R}_{2}+\mathrm{R}_{3} \ldots
\end{gathered}
$$

From this we can derive total resistance in a series circuit as shown above.

## E.M.F and Internal Resistance

All power sources have a value for their EMF. Electromotive force can be defined as the amount of energy supplied by the source per unit charge. It is measured in Volts.

In reality, the terminal potential difference of the power source is never equal to this EMF value. This is because energy is dissipated within the source due to the cell's internal resistance.

Internal resistance can be described as the opposition to the flow of charge within a cell.

$$
\begin{aligned}
& \varepsilon=I R+I r \\
& \varepsilon=V+r l \\
& V=-r l+\varepsilon \\
& y=m x+c
\end{aligned}
$$

You can plot a graph of the terminal voltage against current. The y intercept will be the e.m.f and the gradient will be the negative internal resistance.

## Potential Divider

A potential divider is a combination of two or more resistors in series, which results in the potential difference in the circuit being split into a specific ratio. By choosing the correct values of resistance for the resistors, a desired output voltage (V-out) can be obtained.
A component's pd as a fraction of the total e.m.f will be equal to its resistance as a fraction of the total resistance:

$$
\frac{P . D_{1}}{\Sigma \varepsilon}=\frac{R_{1}}{\Sigma R}
$$



Variable resistors in a potential divider are used to change the voltage supplied to something to a suitable voltage without using a transformer. However, this method wastes power.

Detecting circuits can also be constructed by using a semiconductor, such as an LDR, as the second resistor. This means that when light intensity increases, the output voltage (V-Out) over the LDR will drop below a certain desired level.

